## NSN 5961-01-171-9240

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View Online at https://aerobasegroup.com/nsn/5961-01-171-9240 **Inclosure Material:** Metal **Overall Length:** 1.646 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-48 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.650 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 2.0 forward voltage, peak and 80.0 gate trigger voltage, dc **Current Rating Per Characteristic:** 80.00 milliamperes forward current, total rms preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Internal junction configuration arrangement pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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